Thyristor Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

Between 0.874 inches and 1.030 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

### **Mounting Method:**

Threaded stud

**Features Provided:** 

Hermetically sealed case

### **Overall Width Across Flats:**

Between 1.049 inches and 1.062 inches

Thread Size:

## 0.500 inches

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

800.0 repetitive peak reverse voltage and 960.0 nonrepetitive peak reverse voltage and 800.0 repetitive peak off-state voltage

## **Current Rating Per Characteristic:**

10.00 milliamperes forward current, average nanoamperes and 10.00 milliamperes forward current, total rms and 110.00 amperes forward current, total rms horsepower metric and 1600.00 amperes forward current, total rms watts

# Power Rating Per Characteristic:

400.0 watts small-signal input power, common-collector blank

# Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius case

### **Special Features:**

Junction pattern arrangement: pnpn

### Thread Series Designator:

Unf

# Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0